

FDBS09H04A_F085A/FDPS09H04A_F085A

Smart High Side Switch

Features

- Short circuit protection with latch
- Current limitation
- Overload protection
- Thermal shutdown with restart
- Overvoltage protection (including load dump)
- Loss of ground protection
- Loss of supply protection (with external diode for charged inductive load)
- Very low standby current
- Fast demagnetization of inductive loads
- ESD protection
- Optimized static electromagnetic compatibility
- Diagnostic function - Proportional load current sense (with defined fault signal in case of overload operation, over temperature shutdown and/or short circuit shutdown)
- Qualified to AEC

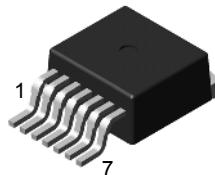
Typical Applications

- Power switch with current sense diagnostic feedback for DC grounded loads
- All types of resistive, inductive, and capacitive loads
- Replace electromechanical relays, fuses and discrete circuits

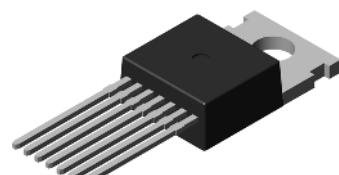
Description

N channel power FET with charge pump, current controlled input and diagnostic feedback with load current sense, integrated in Smart Trench chip on chip technology. Provides embedded protective functions.

TO263-7L



TO220-7L



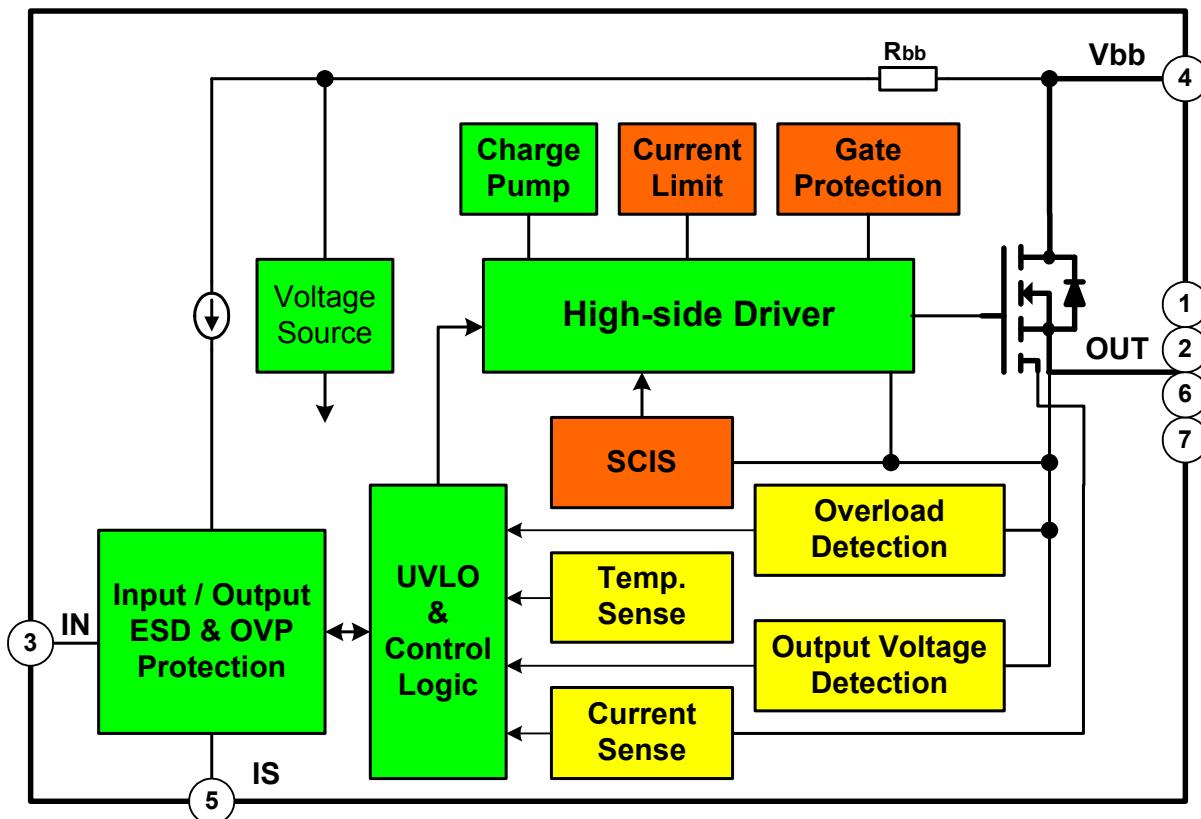
Ordering Information

Part Number	Package	Operating Temperature	Eco Status	Packing Method
FDBS09H04A_F085A	TO263-7L	-40 °C - 150 °C	RoHS	Tape & Reel



For Fairchild's definition of "green" Eco Status, please visit: http://www.fairchildsemi.com/company/green/rohs_green.html.

Block Diagram



Pin Definitions

Pin Number	Pin Name	I/O	Pin Function Description
1	OUT	A	Output to loads; Pins 1, 2, 6 and 7 must be externally shorted
2	OUT	A	Output to loads; Pins 1, 2, 6 and 7 must be externally shorted
3	IN	A	Input; Activates the power switch if shorted to ground
4	V_{bb}	P	Supply Voltage; Pin 4 and tab are internally shorted
5	IS	A	Sense Output, Diagnostic feedback; Provides at normal operation a sense current proportional to the load current; in case of overload, over temperature and/or short circuit a defined current is provided
6	OUT	A	Output to loads; Pins 1, 2, 6 and 7 must be externally shorted
7	OUT	A	Output to loads; Pins 1, 2, 6 and 7 must be externally shorted

Absolute Maximum Ratings

At $T_j=25^\circ\text{C}$ unless otherwise specified.

Parameter	Symbol	Values	Unit
Supply voltage	V_{bb}	38	V
Supply voltage for full short circuit protection ¹⁾	V_{bb}	30	V
Load dump protection $V_{LoadDump} = U_A + V_S$, $U_A=13.5\text{V}$ $R_I=2\Omega$, $R_L=1\Omega$, $t_d=400\text{ms}$, $I_N=\text{Low or High}$	$V_{LoadDump}$ ²⁾	45	V
Load current (short-circuit current)	I_L	Self-limited	A
Operating temperature range	T_j	-40 - 150	$^\circ\text{C}$
Storage temperature range	T_{stg}	-55 - 150	$^\circ\text{C}$
Power Dissipation (DC)	P_{tot}	81	W
Inductive load switch-off energy dissipation ³⁾ Single pulse, $I_L=12.5\text{A}$, $L=5\text{mH}$, $V_{bb}=12\text{V}$, $T_j=150^\circ\text{C}$	EAS	388	mJ
Electrostatic discharge capability (ESD) (Human Body Model)	I_S	V_{ESD}	2
	I_N	V_{ESD}	2
	VBB, Output	V_{ESD}	5
Current through input pin (DC)	I_{IN}	+15, -120	mA
Current through current sense pin (DC)	I_{IS}	+15, -120	mA
Input voltage slew rate $V_{bb} \leq 16\text{V}$	dV_{bb}/dt	self-limited	V/us
Input voltage slew rate $V_{bb} > 16\text{V}$ ⁴⁾		20	

Notes:

- 1) Short circuit is defined as a combination of remaining resistances and inductances. See schematic on page11.
- 2) VLoad dump is setup without the DUT connected to the generator.
- 3) See also diagram on page 11.
- 4) See also on page 7. Slew rate limitation can be achieved by means of using a series resistor R_{IN} in the input path. This resistor is also required for reverse operation. See also page 10.

Electrical Characteristics

At $T_j=25^\circ\text{C}$, $V_{bb}=12\text{V}$ unless otherwise specified.

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Thermal Characteristics						
Thermal resistance	$R_{thJC}^{(5)}$ R_{thJA}	(junction to case) (junction to ambient) device on PCB ⁽⁶⁾ , SMD version only	- - -	0.6 70 35	0.8 - 45	K/W
Load Switching Capability and Characteristics						
On-state resistance (pin 3 to pins 1, 2, 6, 7)	R_{ON}	$V_{IN}=0$, $V_{bb}=5.5\text{V}$, $IL=10\text{A}$, $T_j=25^\circ\text{C}$ $V_{IN}=0$, $V_{bb}=5.5\text{V}$, $IL=10\text{A}$, $T_j=150^\circ\text{C}$ $V_{IN}=0$, $V_{bb}=12\text{V}$, $IL=10\text{A}$, $T_j=25^\circ\text{C}$ $V_{IN}=0$, $V_{bb}=12\text{V}$, $IL=10\text{A}$, $T_j=150^\circ\text{C}$	- - - -	5.5 10 5.5 10	9 15 9 15	$\text{m}\Omega$
Output voltage drop limitation at small load currents (tab to pins 1, 2, 6, 7)	$V_{ON(NL)}$	$T_j=-40 - 150^\circ\text{C}$	-	35	65	mV
Nominal load current (tab to pins 1, 5)	$IL(\text{ISO})$ $IL(\text{NOM})$	ISO Proposal ⁽⁷⁾ : $V_{ON}<=0.5\text{V}$, $TC=85^\circ\text{C}$, $T_j<=150^\circ\text{C}$ SMD ^{(6) (7)} : $V_{ON}<= 0.5\text{V}$, $T_a=85^\circ\text{C}$, $T_j<=150^\circ\text{C}$	38 12	48 14	- -	A
Turn-on time (to 90% VOUT) Turn-off time (to 10% VOUT)	t_{on} t_{off}	$RL=2.2\Omega$, $T_j = -40 - 150^\circ\text{C}$	- -	180 150	400 500	us
Slew rate on (25% to 50% VOUT)	dV / dt_{on}	$RL=2.2\Omega$, $T_j = -40 - 150^\circ\text{C}$	-	0.2	0.45	V/us
Slew rate off (50% to 25% VOUT)	$-dV / dt_{off}$	$RL=2.2\Omega$, $T_j = -40 - 150^\circ\text{C}$	-	0.2	0.55	V/us
Operating Parameters						
Operating Voltage ($V_{IN}=0$)	$V_{bb(\text{ON})}$	$T_j = -40 - 150^\circ\text{C}$	5.5		38	V
Under voltage shutdown ⁽⁸⁾	$V_{bb(u)}$		-	1.5	3.5	V
Under voltage restart of charge pump	$V_{bb(\text{ucp})}$			3.7	5.5	V
Over voltage protection ⁽⁹⁾	$V_{Z,IN}$	$I_{bb}=15\text{mA}$, $T_j = -40 - 150^\circ\text{C}$	42.5	47.3	-	V
Standby current	$I_{bb(\text{off})}$	$I_{IN}=0$, $T_j = -40 - 120^\circ\text{C}$ $I_{IN}=0$, $T_j = 150^\circ\text{C}$	- -	0.8 8	5.3 20	μA
Reverse Battery⁽¹⁰⁾						
Reverse battery voltage	$-V_{bb}$	$IL=-10\text{A}$, $RIS=1\text{k}\Omega$	-	-	18	V
On-state resistance (pin 4, tab to pins 1, 2, 6, 7) ⁽⁸⁾	$RON(\text{REV})$	$V_{bb}=-8\text{V}$, $V_{IN}=0$, $IL=-10\text{A}$, $RIS=1\text{k}\Omega$, $T_j=25^\circ\text{C}$ $V_{bb}=-8\text{V}$, $V_{IN}=0$, $IL=-10\text{A}$, $RIS=1\text{k}\Omega$, $T_j=150^\circ\text{C}$ $V_{bb}=-12\text{V}$, $V_{IN}=0$, $IL=-10\text{A}$, $RIS=1\text{k}\Omega$, $T_j=25^\circ\text{C}$ $V_{bb}=-12\text{V}$, $V_{IN}=0$, $IL=-10\text{A}$, $RIS=1\text{k}\Omega$, $T_j=150^\circ\text{C}$	- - - -	6.1 13 6.1 10	13 18 11.5 17	$\text{m}\Omega$
Integrated resistor in V_{bb} line	R_{bb}	$I_s=1\text{mA}$, $V_{IN}=5\text{V}$ @ $T_j=125^\circ\text{C}$	65	85	110	Ω
Inverse operation⁽¹¹⁾						
Output voltage drop (pin 4, tab to pins 1, 2, 6, 7) ⁽⁸⁾	$-V_{ON(\text{inv})}$	$IL=-10\text{A}$, $RIS=1\text{k}\Omega$, $T_j=25^\circ\text{C}$ $IL=-10\text{A}$, $RIS=1\text{k}\Omega$, $T_j=150^\circ\text{C}$	- -	800 600	- -	mV
Turn-on delay after inverse operation	$td(\text{inv})$	$IL> 0\text{A}$ ⁽⁸⁾ $V_{IN(\text{inv})}=V_{IN(\text{fwd})}=0\text{V}$	-	1	-	ms

Notes:

5) Thermal resistance R_{thCH} case to heatsink (about 0.5... 0.9 K/W with silicone paste) not included!

6) Device on 76.2mm * 114mm * 1.57mm glass epoxy PCB. Still air conditions.

7) Not subject to production test. Parameters are calculated from Ron and Rthjc or Rthja.

8) Not subject to production test, specified by design.

9) See also VON(CL) in circuit diagram page 8.

10) For operation at voltages higher than $|16\text{V}|$ please see required schematic on page 9.

11) Permanent Inverse operation results eventually in a current flow via the intrinsic diode of the power DMOS. In this case the device switches on with a time delay $td(\text{inv})$ after the transition from inverse to forward mode.

Electrical Characteristics

At $T_j=25^\circ\text{C}$, $V_{bb}=12\text{V}$ unless otherwise specified

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Protection Functions¹²⁾						
Short circuit current limit (pin 4, tab to pins 1, 2, 6, 7) at $V_{ON}=6\text{V}$ ¹³⁾ ¹⁴⁾	IL6(SC)	$T_j=-40^\circ\text{C}$ $T_j=25^\circ\text{C}$ $T_j=150^\circ\text{C}$	- - 85	130 120 110	160	A
Short circuit current limit (pin 4, tab to pins 1, 2, 6, 7) at $V_{ON}=12\text{V}$ ¹³⁾	IL12(SC)	$T_j=-40^\circ\text{C}$ $T_j=25^\circ\text{C}$ $T_j=150^\circ\text{C}$	- - 55	93 85 73	125	A
Short circuit current limit (pin 4, tab to pins 1, 2, 6, 7) at $V_{ON}=18\text{V}$ ¹³⁾ ¹⁴⁾	IL18(SC)	$T_j=-40^\circ\text{C}$ $T_j=25^\circ\text{C}$ $T_j=150^\circ\text{C}$	- - 41	75 68 61	100	A
Short circuit current limit (pin 4, tab to pins 1, 2, 6, 7) at $V_{ON}=24\text{V}$ ¹³⁾	IL24(SC)	$T_j=-40^\circ\text{C}$ $T_j=25^\circ\text{C}$ $T_j=150^\circ\text{C}$	- - 20	53 47 41	75	A
Short circuit current limit (pin 4, tab to pins 1, 2, 6, 7) at $V_{ON}=30\text{V}$ ¹³⁾	IL30(SC)	$T_j=-40^\circ\text{C}$ $T_j=25^\circ\text{C}$ $T_j=150^\circ\text{C}$	- - 18	34 31 28	50	A
Short circuit shutdown detection voltage ¹⁴⁾	$V_{ON}(\text{SC})$		2.5	3.5	4.5	V
Short circuit shutdown delay after input current positive slope Min. value valid only if "off-signal" time exceeds 30us	$t_d(\text{SC1})$	$V_{ON} > V_{ON}(\text{SC}), T_j=-40 \sim 150^\circ\text{C}$	370	520	700	us
Output clamp(inductive load switch off) at $V_{OUT}=V_{bb}-V_{ON}(\text{CL})(\text{overvoltage})$ ¹⁵⁾	$V_{ON}(\text{CL})$	$I_L=40\text{mA}$	38.5	41.5	-	V
Thermal overload trip temperature ¹⁴⁾	T_{jt}		165	178	-	$^\circ\text{C}$
Thermal hysteresis ¹⁴⁾	ΔT_{jt}		-	10	-	K

Notes:

12) Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

13) Short circuit current limit for max. duration of $t_d(\text{SC1})$, prior to shutdown, see also Figures 3.x on page 14 and 15.

14) Not subject to production test, specified by design.

15) See also Figure 2b on page 14.

Electrical Characteristics

At $T_j=25^\circ\text{C}$, $V_{bb}=12\text{V}$ unless otherwise specified.

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
Diagnostic Characteristics						
Current sense ratio, static on-condition KILIS = I_L : $I_{IS,min}^{16)}$ $V_{IS} < V_{OUT}-5\text{V}$, $V_{bIN} > 4.5\text{V}$	KILIS	$I_L=35\text{A}, T_j=-40^\circ\text{C}$ $I_L=35\text{A}, T_j=25^\circ\text{C}$ $I_L=35\text{A}, T_j=125^\circ\text{C}$ $I_L=15\text{A}, T_j=-40^\circ\text{C}$ $I_L=15\text{A}, T_j=25^\circ\text{C}$ $I_L=15\text{A}, T_j=125^\circ\text{C}$ $I_L=2.5\text{A}, T_j=-40^\circ\text{C}$ $I_L=2.5\text{A}, T_j=25^\circ\text{C}$ $I_L=2.5\text{A}, T_j=125^\circ\text{C}$ $I_L=0.5\text{A}, T_j=-40^\circ\text{C}$ $I_L=0.5\text{A}, T_j=25^\circ\text{C}$ $I_L=0.5\text{A}, T_j=125^\circ\text{C}$ $I_{IN}=0$ (e.g. during deenergizing of inductive loads)	- 11000 11000 11000 9300 10500 11000 7800 8200 8000 5800 7700 8100 -	13200 13200 13275 13250 13000 13000 12900 13100 13400 13450 12500 13000 13700	- 15000 15000 15000 18000 17000 16000 18200 18500 18850 17900 18500 19200 -	- - - - - - - - - - - - - -
Sense current under fault conditions ¹⁷⁾	$I_{IS,fault}$	$V_{ON} > 1\text{V}$, typ $T_j = -40 - 150^\circ\text{C}$	3.5	5.2	7.5	mA
Sense saturation current	$I_{IS,lim}$	$V_{ON} < 1\text{V}$, typ $T_j = -40 - 150^\circ\text{C}$	3.5	5.8	8.5	mA
Fault-sense signal delay after input current positive slope	$t_{delay(fault)}$	$V_{ON} > 1\text{V}$, typ $T_j = -40 - 150^\circ\text{C}$	350	500	650	us
Current sense leakage current	$I_{IS(LL)}$	$I_{IN} = 0$	-	0	0.5	uA
Current sense offset current	$I_{IS(LH)}$	$V_{IN} = 0, I_L \leq 0$	-	0	1	uA
Minimum load current for sense functionality	$I_L(MIN)$	$V_{IN} = 0, T_j = -40 - 150^\circ\text{C}$	70	-	-	mA
Current sense settling time to $I_{IS,static}$ after input current positive slope ¹⁸⁾	$t_{on}(IS)$	$I_L = 0 \rightarrow 20\text{A}, T_j = -40 - 150^\circ\text{C}$	-	300	650	us
Current sense settling time during on condition ¹⁸⁾	$t_{slc}(IS)$	$I_L = 10 \rightarrow 20\text{A}, T_j = -40 - 150^\circ\text{C}$	-	50	100	us
Overvoltage protection	$V_{Z,IS}$	$I_{bb} = 15\text{mA}, T_j = -40 - 150^\circ\text{C}$	42.5	47.3	-	V
Input						
Required current capability of input switch	$I_{IN(on)}$	$T_j = -40 - 150^\circ\text{C}$	-	1.5	3.0	mA
Input current for turn-off	$I_{IN(off)}$	$T_j = -40 - 150^\circ\text{C}$	-	-	15	uA

Notes:

16) See also Figures 4.x and 6.x on page 15 and 16.

17) Fault conditions are overload during on (i.e. $V_{ON}>1\text{V}$ typ.), over temperature and short circuit; see also truth table on page 7.

18) Not subject to production test, specified by design.

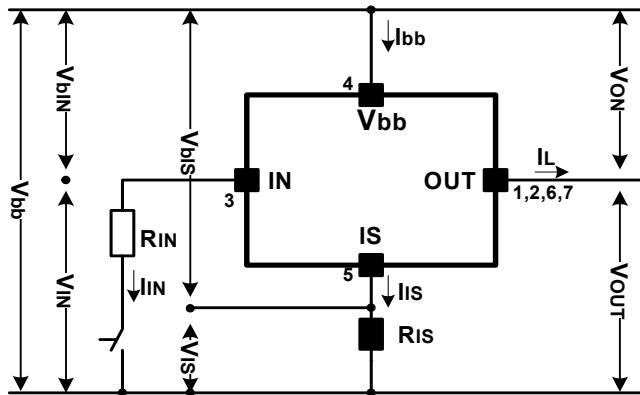
Application Information

1. Truth Table

Sense current under fault conditions	Input Current Level	Output Level	Current Sense
Normal operation	L H	L H	= 0 (IIS(LL)) nominal
Overload ¹⁹⁾	L H	L H	= 0 (IIS(LL)) IIS,fault
Short circuit to GND ²⁰⁾	L H	L L	= 0 (IIS(LL)) IIS,fault
Over temperature	L H	L L	= 0 (IIS(LL)) IIS,fault
Short circuit to V _{bb}	L H	H H	= 0 (IIS(LL)) < nominal ²¹⁾
Open load	L H	Z H	= 0 (IIS(LL)) = 0 (IIS(LH))

L = "Low" Level, Z = High impedance, potential depends on external circuit, H = "HIGH" Level

2.Terms



Notes:

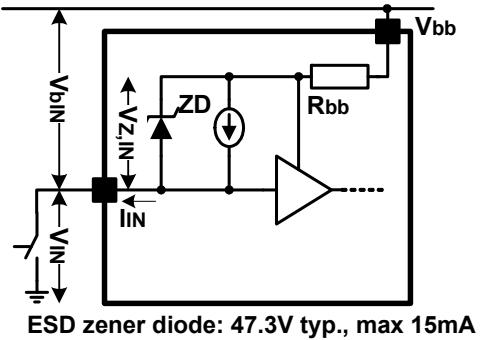
19) Overload is detected at the following condition: 1V (typ.) < V_{ON} < 3.5V (typ.). See also page 10.

20) Short Circuit is detected at the following condition: V_{ON} > 3.5V (typ.). See also page 11.

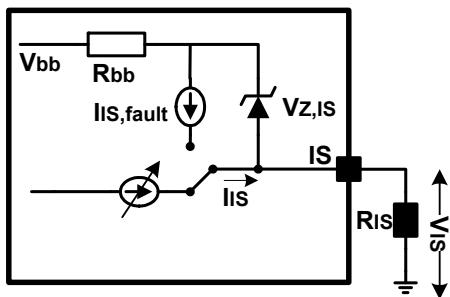
21) Low ohmic short to V_{bb} may reduce the output current IL and therefore also the sense current IIS.

3. Detailed Function Blocks

3.1 Input circuit (ESD protection)



3.2 Current sense output

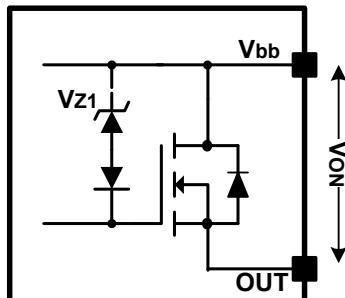


$V_{Z,IS} = 47.3V$ (typ.), $R_{IS} = 1\text{K}\Omega$ nominal (or $1\text{K}\Omega /n$, if n devices are connected in parallel). $IS = IL/kilis$ can be only driven by the internal circuit as long as $V_{OUT} - V_{IS} > 5\text{V}$. Therefore R_{IS} should be less than

$$\frac{V_{bb} - 5\text{V}}{8.5\text{mA}}$$

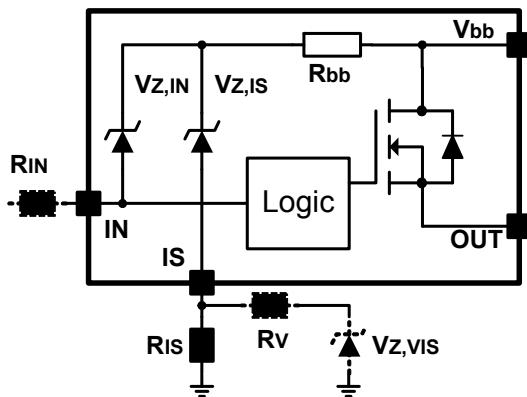
Note: For large values of R_{IS} the voltage V_{IS} can reach almost V_{bb} . See also over voltage protection. If you don't use the current sense output in your application, you can leave it open.

3.3 Inductive and over voltage output clamp



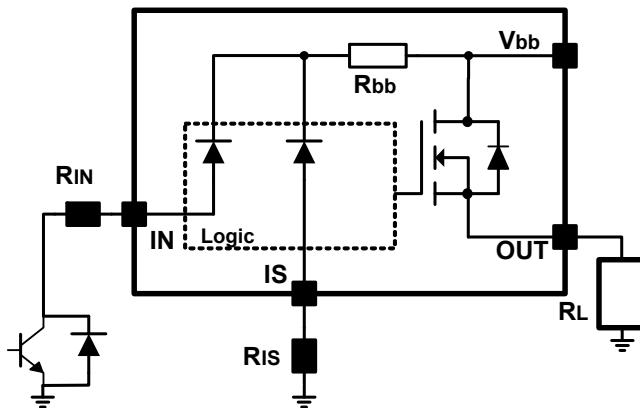
V_{ON} is clamped to $V_{ON(CL)} = 41.5\text{V}$ typical

3.4 Overvoltage protection of logic part



$R_{bb} = 85\Omega$ typ., $V_{Z,IN} = V_{Z,IS} = 47.3V$ typ., $R_{IS} = 1K\Omega$ nominal. Note that when over voltage exceeds 47.3V typ. a voltage above 5V can occur between IS and GND, if R_V , $V_{Z,VIS}$ are not used.

3.5 Reverse battery protection

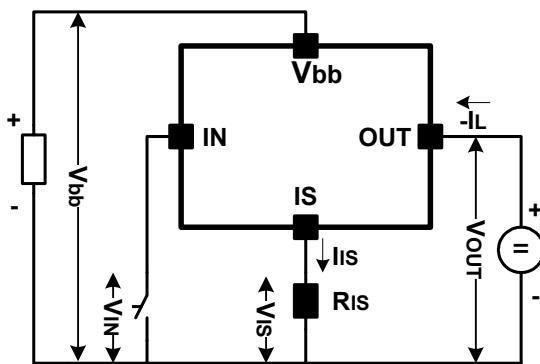


R_{IS} typ. $1K\Omega$. Add R_{IN} for reverse battery protection in application with V_{bb} above 16V;

$$\frac{1}{R_{IN}} + \frac{1}{R_{IS}} > \frac{0.082A}{|V_{bb}| - 9V}$$

To minimize power dissipation at reverse battery operation, the overall current into the IN and IS pin should be about 82mA. The current can be provided by using a small signal diode D in parallel to the input switch, by using a MOSFET input switch or by properly adjusting the current through R_{IS} . Since the current via R_{bb} generates additional heat in the device, this has to be taken into account in the overall thermal consideration.

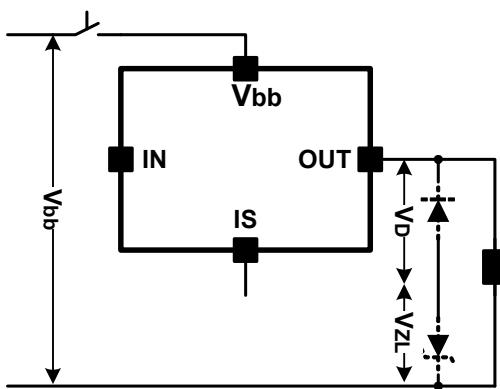
3.6 Inverse load current operation



The device can be operated in inverse load current mode ($V_{OUT} > V_{bb} > 0V$). The current sense feature is not available during this kind of operation ($I_{IS} = 0$). In case of inverse operation the intrinsic drain source diode is eventually conducting resulting in considerably increased power dissipation. The transition from inverse to forward mode can result in a delayed switch on.

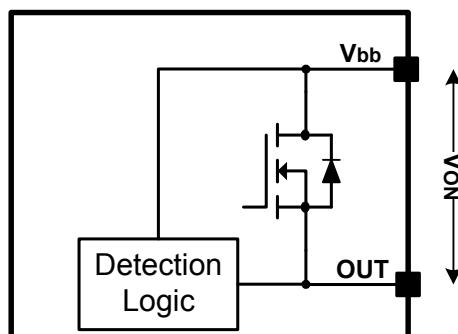
Note: Temperature protection during inverse load current operation is not possible!

3.7 V_{bb} disconnect with energized inductive load



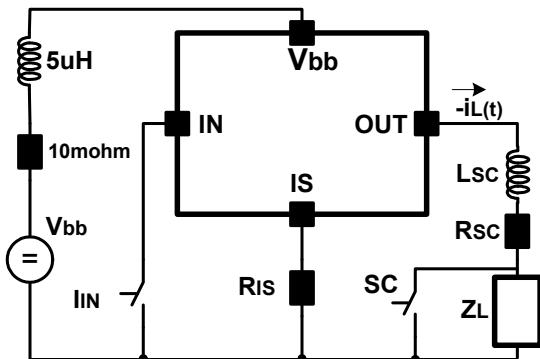
Provide a current path with load current capability by using a diode, a Z-diode, or a varistor($V_{ZL} + V_D < 38V$ if $R_{IN} = 0$). For higher clamp voltages currents at IN and IS have to be limited to 120 mA.

3.8 Overload detection



Fault Condition: $V_{ON} > 1V$ typ.

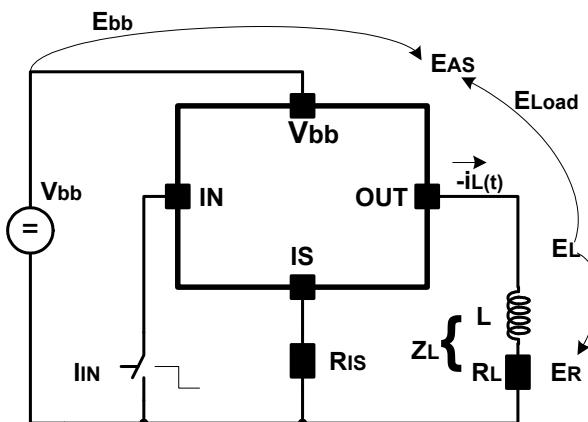
3.9 Short circuit



Fault Condition: $V_{ON} > V_{ON(SC)}$ (3.5V typ.) and $t > t_d(SC)$ (typ. 650us)

Short circuit is a combination of primary and secondary impedances and resistances.

3.10 Inductive load switch-off energy dissipation



Energy stored in load inductance:

$$E_L = 1/2 \cdot L \cdot I_L^2$$

While demagnetizing load inductance, the energy dissipated in MOSFET is

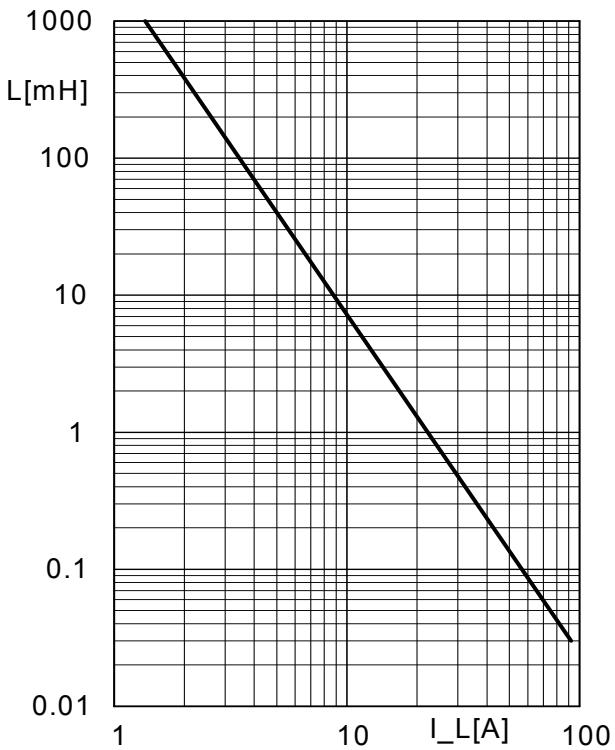
$$E_{AS} = E_{bb} + E_L - E_R = \int V_{ON(CL)} \cdot i_L(t) dt$$

with an approximate solution for $R_L > 0$ $V_{out(CL)} = V_{ON(CL)} - V_{bb}$:

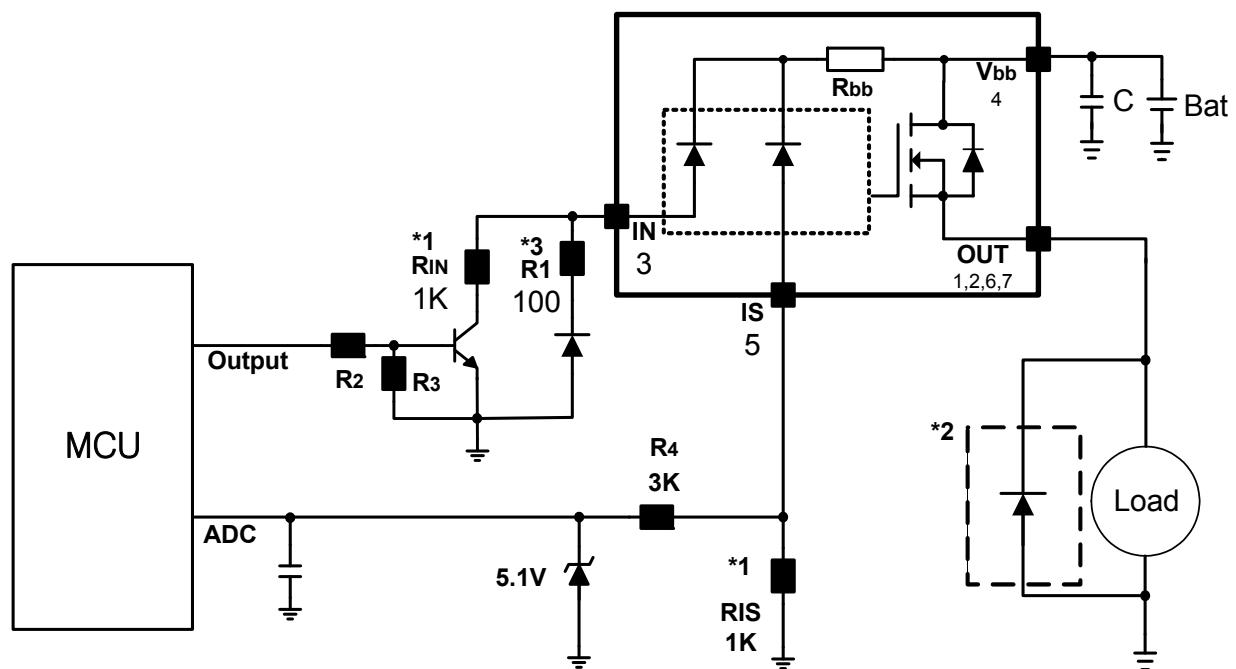
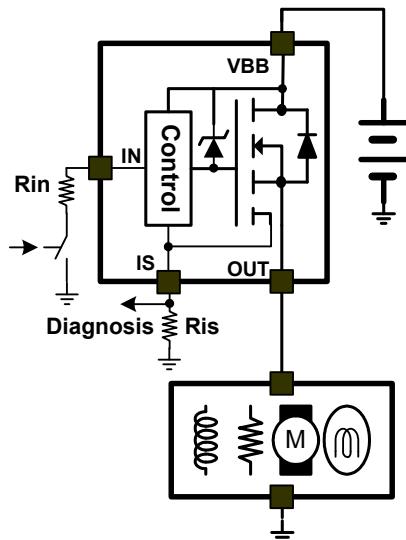
$$E_{AS} = \frac{I_L \cdot L}{2 \cdot R_L} (V_{ON(CL)}) \ln \left(1 + \frac{I_L \cdot R_L}{|V_{OUT(CL)}|} \right)$$

3.11 Maximum allowable load inductance for a single switch off

$L=f(I_L)$; $T_j = 150^\circ\text{C}$, $V_{bb}=12\text{V}$, $R_L = 0\Omega$



Typical Application Circuit



1) R_{is} and R_{in} is recommended as 1k

2) Put diode or capacitor between load to protect device or to remove noise.

3) For reverse battery protection function, R_1 should be used less than 120Ω at -18V.

Timing Diagrams

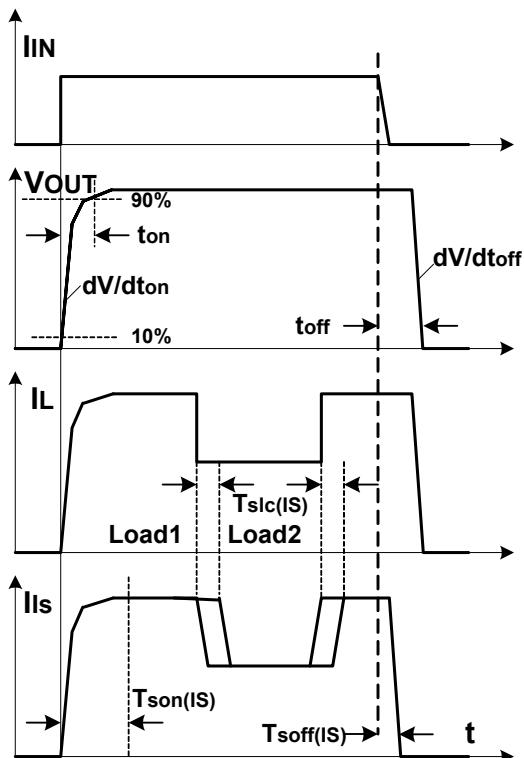


Figure 1a. Switching a resistive load, change of load current in ON-condition

The sense signal is not valid during a settling time after turn-on/off and after change of load current

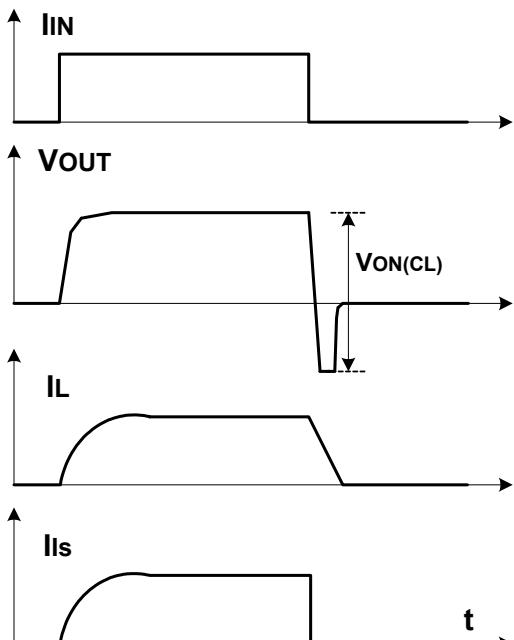


Figure 2b. Switching an inductive load

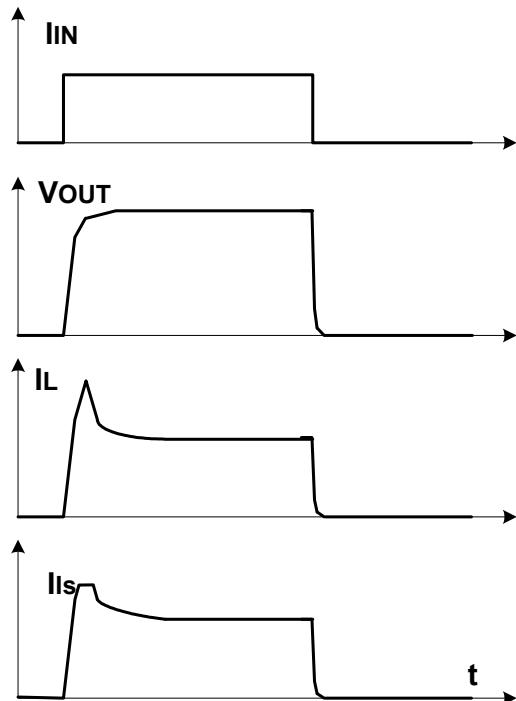


Figure 2a. Switching motors and lamps

As long as $V_{BLS} < V_{Z,IS}$ the sense current will never exceed $I_{IS,fault}$ and/or $I_{IS,lim}$

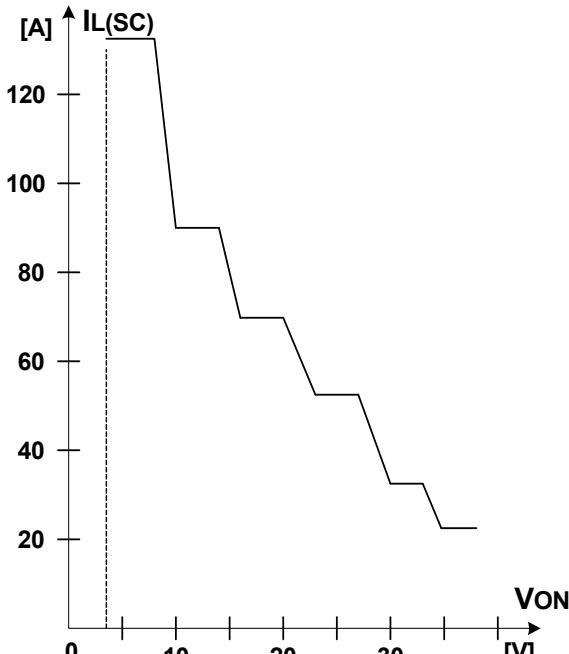


Figure 3a. Typical current limitation characteristic

In case of $V_{ON} > V_{ON(SC)}$ (typ. 3.5V) the device will be switched off by internal short circuit detection

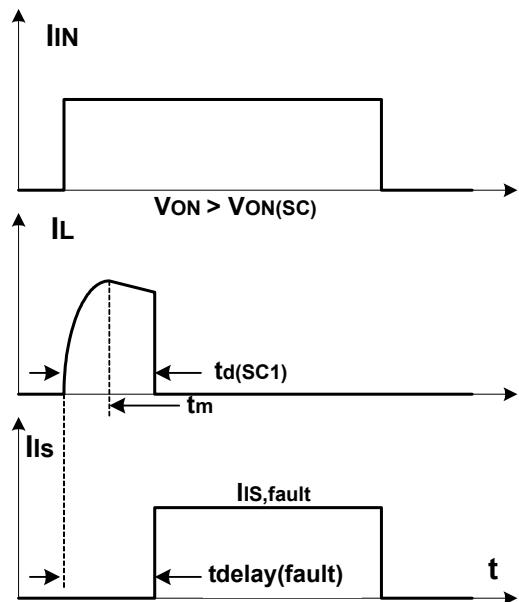


Figure 3b. Short circuit type one:
shut down by short circuit detection, reset by $I_{IN}=0$

Shut down remains latched until next reset via input

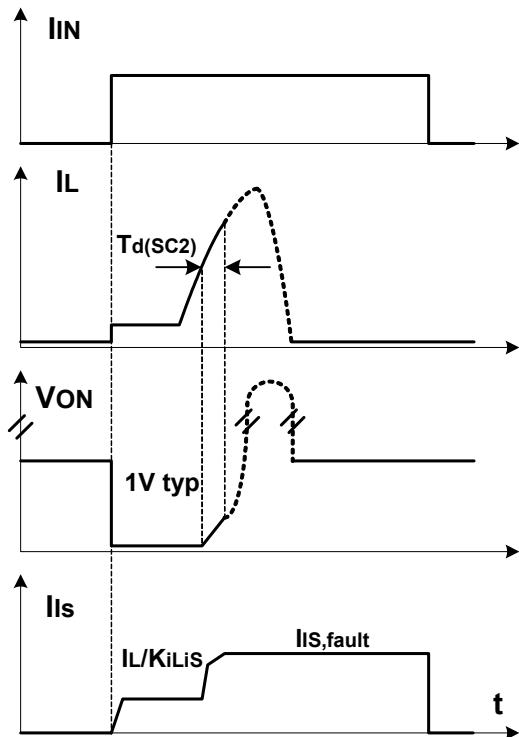


Figure 3c. Short circuit type two:
shut down by short circuit detection, reset by $I_{IN}=0$

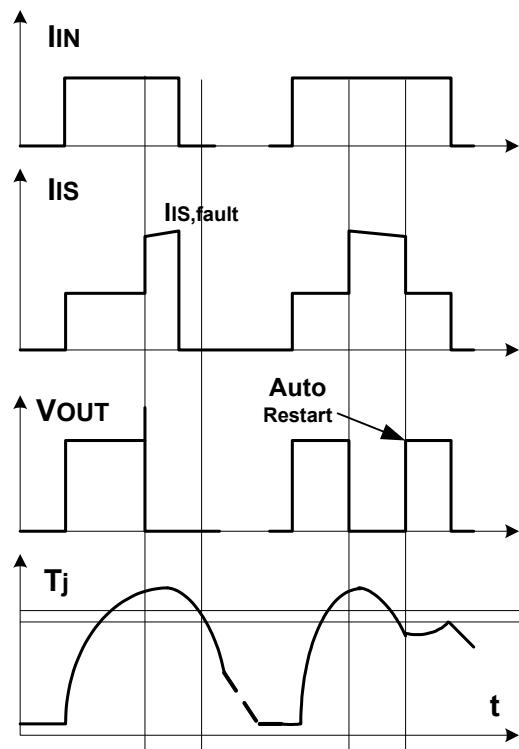


Figure 4a. Over temperature Reset if $T_j < T_{jt}$

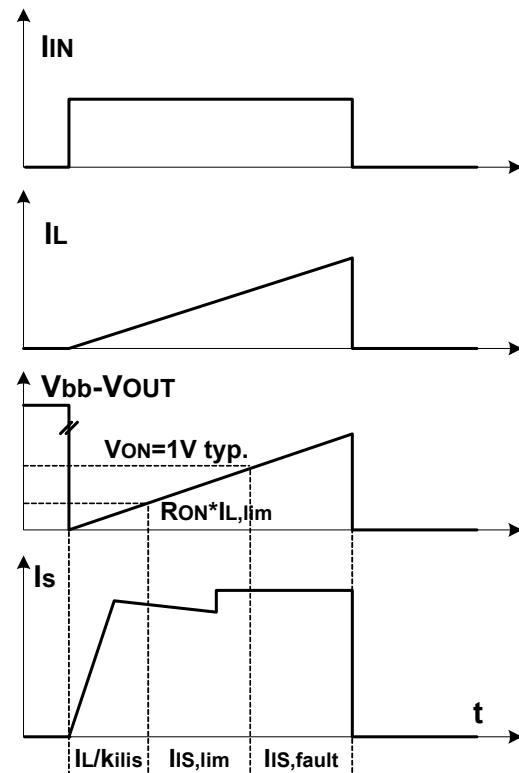


Figure 4b. Overload Reset if $T_j < T_{jt}$

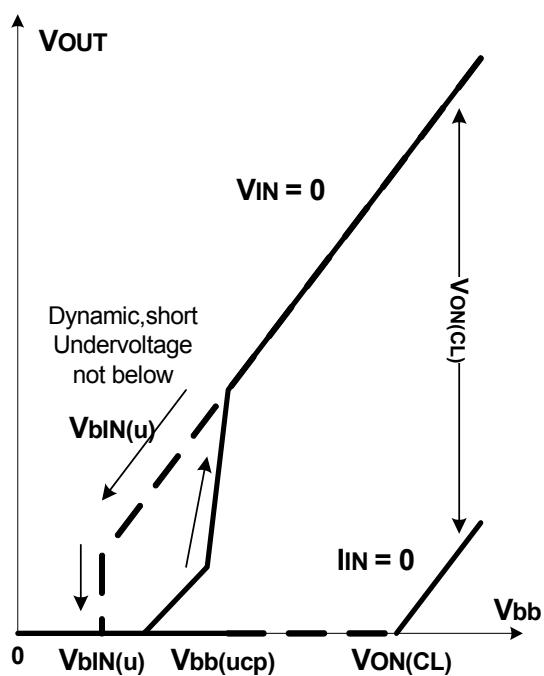


Figure 5. Under voltage restart of charge pump and over voltage clamp

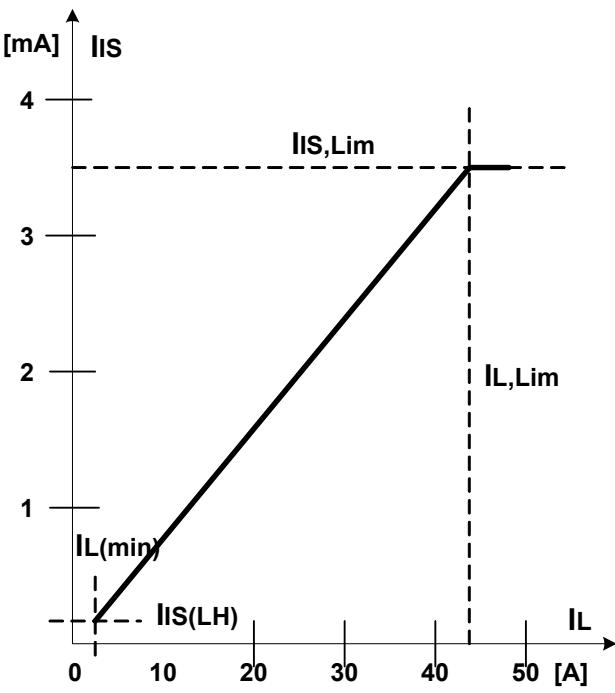


Figure 6a. Current sense versus load current

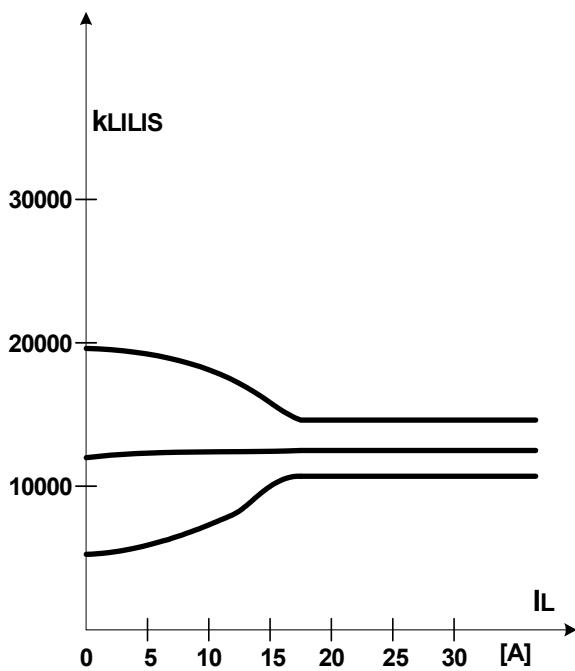


Figure 6b. Current sense ratio

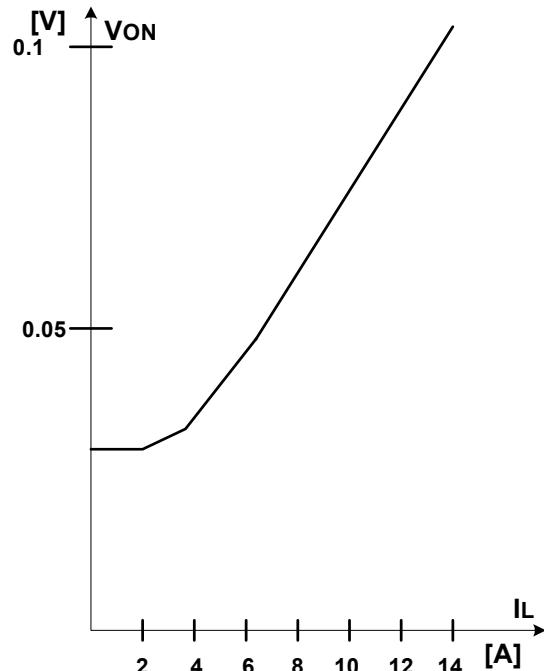
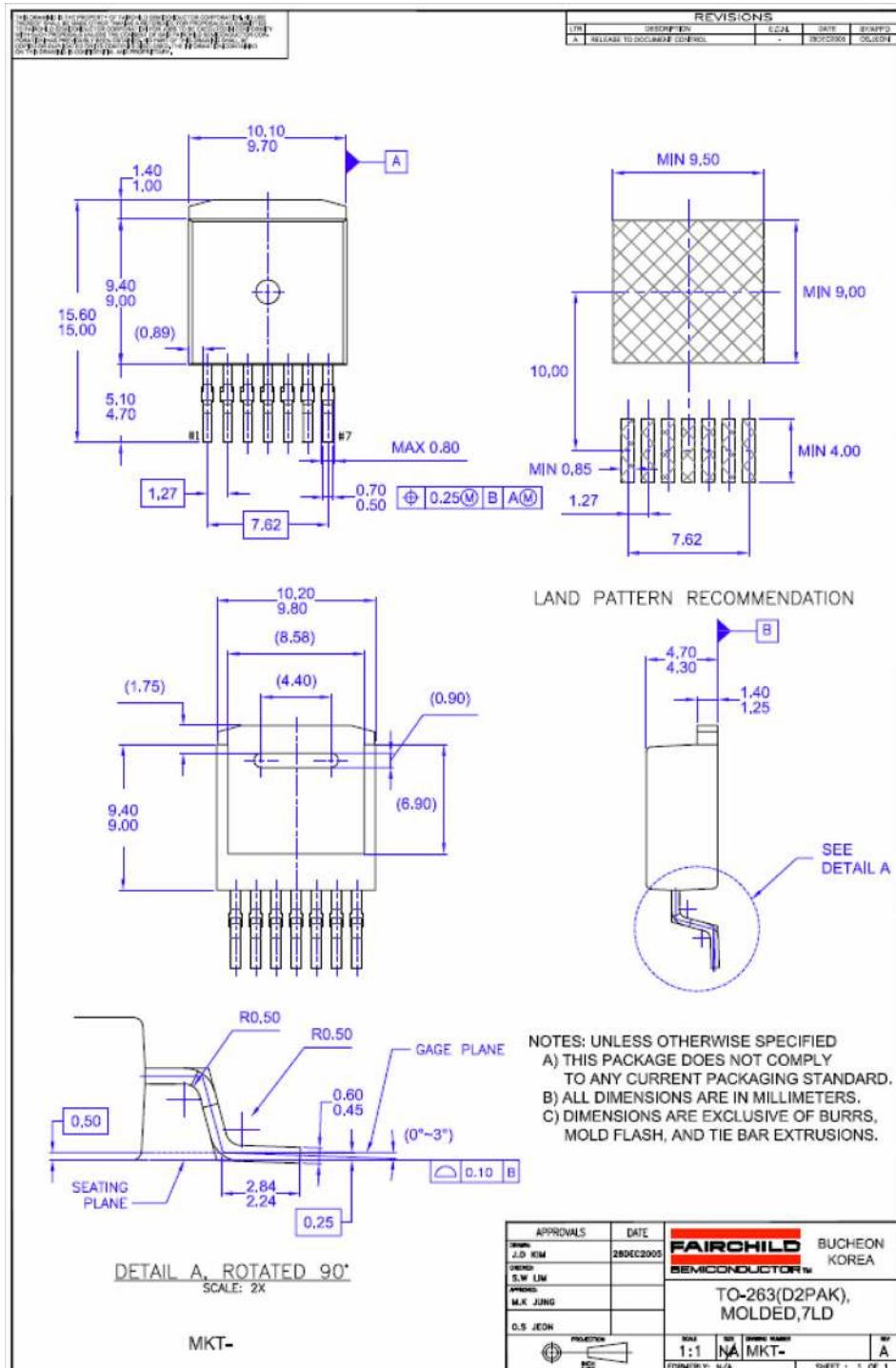
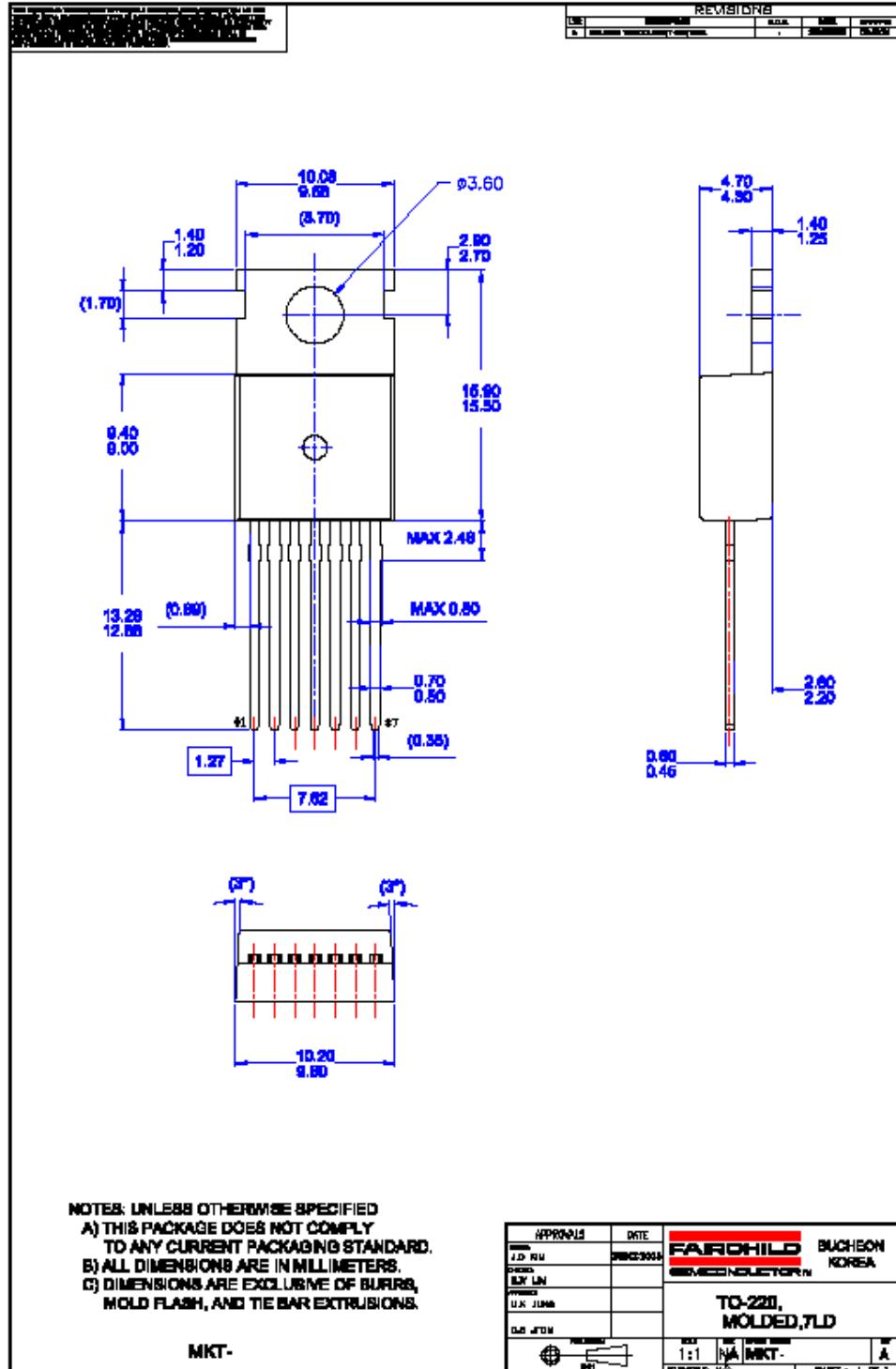


Figure 7. Output voltage drop versus load current

Package Dimensions





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